

# ANTREX Electronics

## Electronic Components Sourcing Information

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### Product Reference Information

**Part Number:** BT1308-400D,412  
**Manufacturer:** NXP USA Inc.  
**Package:** TO-92-3  
**Availability:** Please confirm with sales

**Product Page:**

<https://antrexco.com/product/details/nxp-usa-inc/bt1308-400d-412.html>

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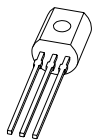
CoC / RoHS / REACH documents available on request

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**Note:**

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.



# BT1308 series D

Triacs logic level

Rev. 01 — 26 February 2008

Product data sheet

## 1. Product profile

### 1.1 General description

Passivated sensitive gate triacs in a SOT54 plastic package

### 1.2 Features

- Sensitive gate
- Direct interfacing to logic level ICs
- Gate triggering in four quadrants
- Direct interfacing to low-power gate drive circuits

### 1.3 Applications

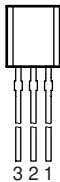
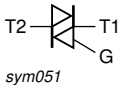
- General purpose switching and phase control
- Low-power AC fan speed control

### 1.4 Quick reference data

- $V_{DRM} \leq 400 \text{ V}$  (BT1308-400D)
- $V_{DRM} \leq 600 \text{ V}$  (BT1308-600D)
- $I_{TSM} \leq 9 \text{ A}$  ( $t = 20 \text{ ms}$ )
- $I_{GT} \leq 5 \text{ mA}$
- $I_{GT} \leq 7 \text{ mA}$  (T2– G+)
- $I_{T(RMS)} \leq 0.8 \text{ A}$

## 2. Pinning information

Table 1. Pinning

| Pin | Description          | Simplified outline                                                                   | Graphic symbol                                                                        |
|-----|----------------------|--------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|
| 1   | main terminal 2 (T2) |  |  |
| 2   | gate (G)             |                                                                                      |                                                                                       |
| 3   | main terminal 1 (T1) |                                                                                      |                                                                                       |
|     |                      | SOT54 (TO-92)                                                                        |                                                                                       |

### 3. Ordering information

**Table 2.** Ordering information

| Type number | Package |                                                             | Version |
|-------------|---------|-------------------------------------------------------------|---------|
|             | Name    | Description                                                 |         |
| BT1308-400D | TO-92   | plastic single-ended leaded (through hole) package; 3 leads | SOT54   |
| BT1308-600D |         |                                                             |         |

### 4. Limiting values

**Table 3.** Limiting values

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

| Symbol              | Parameter                            | Conditions                                                                                                   | Min | Max  | Unit             |
|---------------------|--------------------------------------|--------------------------------------------------------------------------------------------------------------|-----|------|------------------|
| $V_{\text{DRM}}$    | repetitive peak off-state voltage    | BT1308-400D                                                                                                  | -   | 400  | V                |
|                     |                                      | BT1308-600D                                                                                                  | -   | 600  | V                |
| $I_{\text{T(RMS)}}$ | RMS on-state current                 | full sine wave; $T_{\text{lead}} \leq 55\text{ °C}$ ; see <a href="#">Figure 4</a> and <a href="#">5</a>     | -   | 0.8  | A                |
| $I_{\text{TSM}}$    | non-repetitive peak on-state current | full sine wave; $T_j = 25\text{ °C}$ prior to surge; see <a href="#">Figure 2</a> and <a href="#">3</a>      |     |      |                  |
|                     |                                      | $t = 20\text{ ms}$                                                                                           | -   | 9    | A                |
|                     |                                      | $t = 16.7\text{ ms}$                                                                                         | -   | 10   | A                |
| $I^2t$              | $I^2t$ for fusing                    | $t_p = 10\text{ ms}$                                                                                         | -   | 0.32 | A <sup>2</sup> s |
| $dI_{\text{T}}/dt$  | rate of rise of on-state current     | $I_{\text{TM}} = 1\text{ A}$ ; $I_{\text{G}} = 20\text{ mA}$ ; $dI_{\text{G}}/dt = 0.2\text{ A}/\mu\text{s}$ |     |      |                  |
|                     |                                      | T2+ G+                                                                                                       | -   | 50   | A/ $\mu\text{s}$ |
|                     |                                      | T2+ G-                                                                                                       | -   | 50   | A/ $\mu\text{s}$ |
|                     |                                      | T2- G-                                                                                                       | -   | 50   | A/ $\mu\text{s}$ |
|                     |                                      | T2- G+                                                                                                       | -   | 10   | A/ $\mu\text{s}$ |
| $I_{\text{GM}}$     | peak gate current                    |                                                                                                              | -   | 1    | A                |
| $P_{\text{GM}}$     | peak gate power                      |                                                                                                              | -   | 5    | W                |
| $P_{\text{G(AV)}}$  | average gate power                   | over any 20 ms period                                                                                        | -   | 0.1  | W                |
| $T_{\text{stg}}$    | storage temperature                  |                                                                                                              | -40 | +150 | °C               |
| $T_j$               | junction temperature                 |                                                                                                              | -   | 125  | °C               |

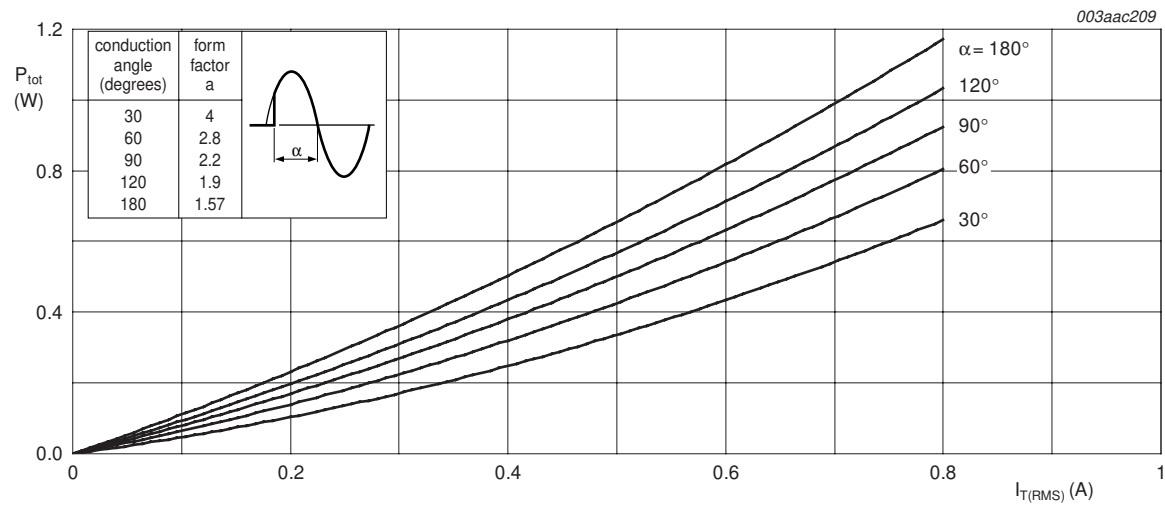


Fig 1. Total power dissipation as a function of RMS on-state current; maximum values

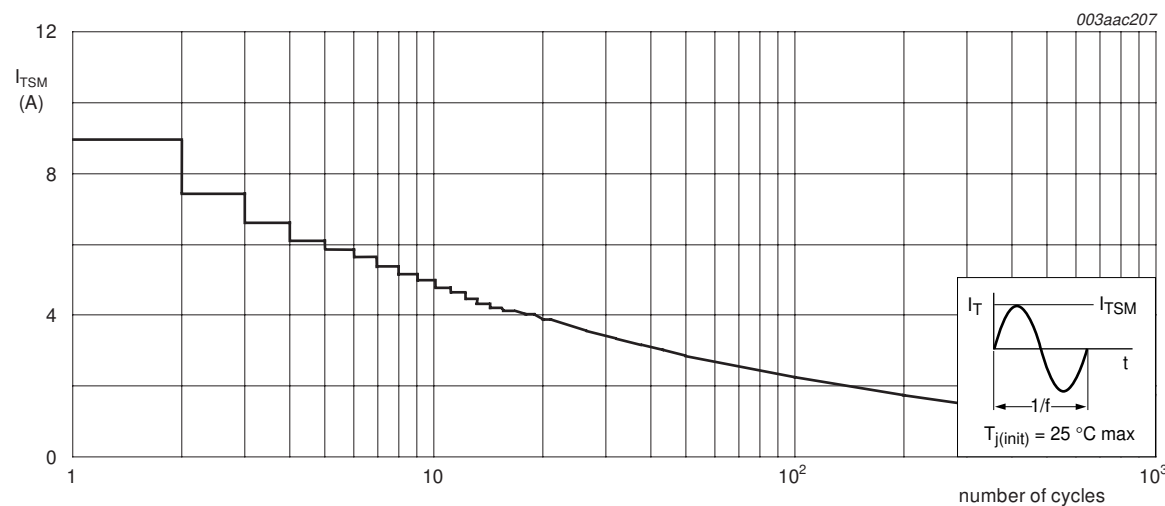


Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

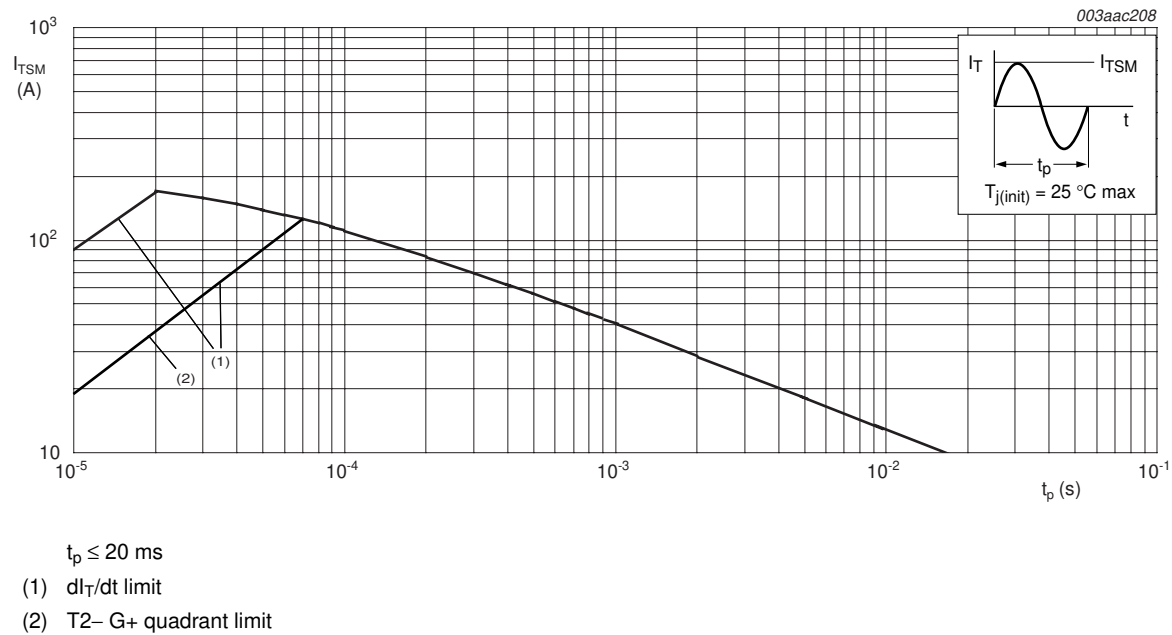


Fig 3. Non-repetitive peak on-state current as a function of pulse width; maximum values

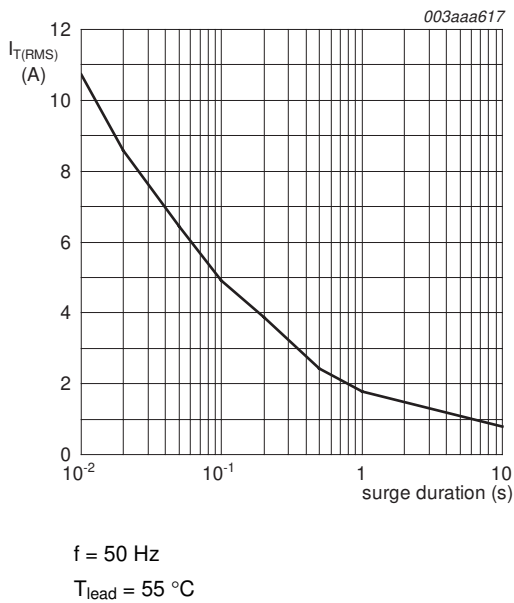


Fig 4. RMS on-state current as a function of surge duration; maximum values

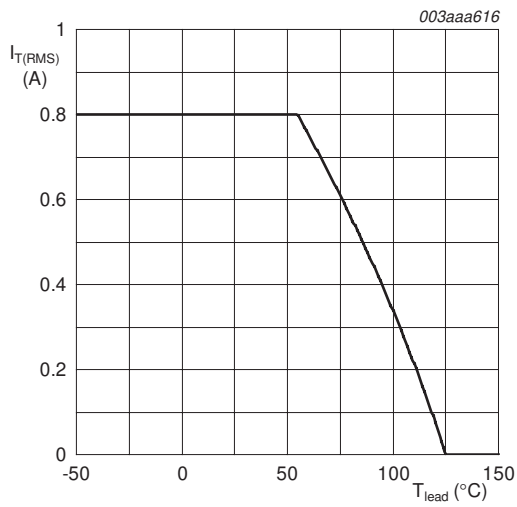
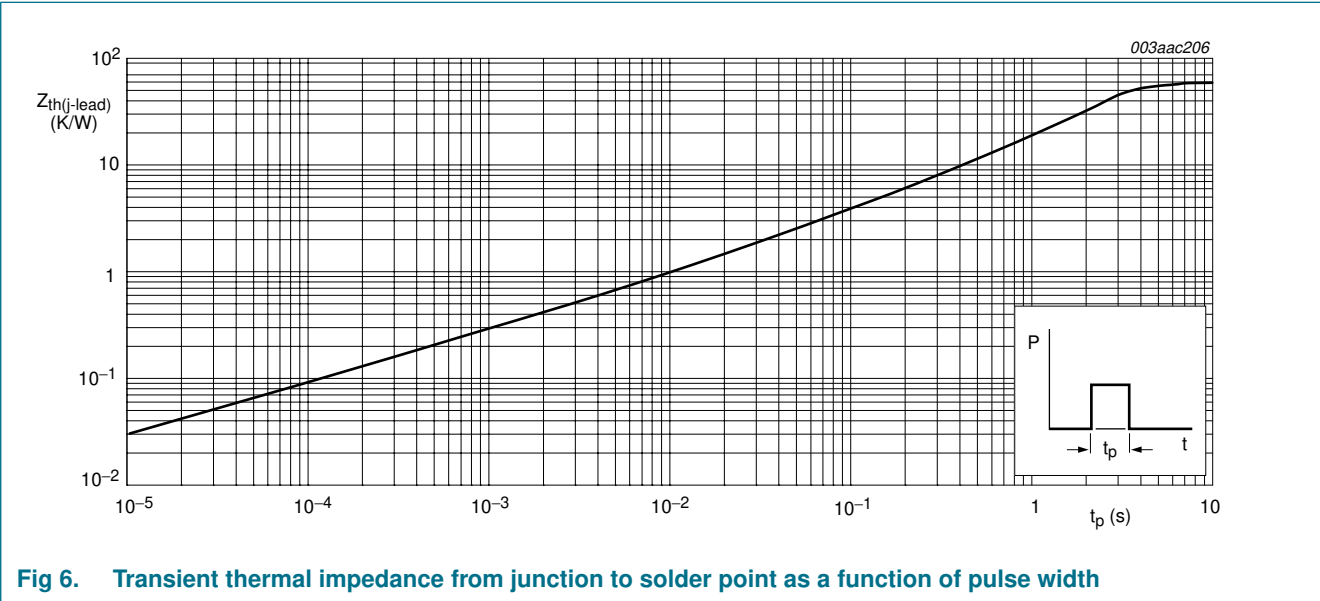


Fig 5. RMS on-state current as a function of lead temperature; maximum values

5. Thermal characteristics

Table 4. Thermal characteristics

| Symbol           | Parameter                                   | Conditions                                                                                | Min | Typ | Max | Unit |
|------------------|---------------------------------------------|-------------------------------------------------------------------------------------------|-----|-----|-----|------|
| $R_{th(j-lead)}$ | thermal resistance from junction to lead    | full cycle                                                                                | -   | -   | 60  | K/W  |
| $R_{th(j-a)}$    | thermal resistance from junction to ambient | full cycle; printed-circuit board mounted; lead length 4 mm; see <a href="#">Figure 6</a> | -   | 150 | -   | K/W  |

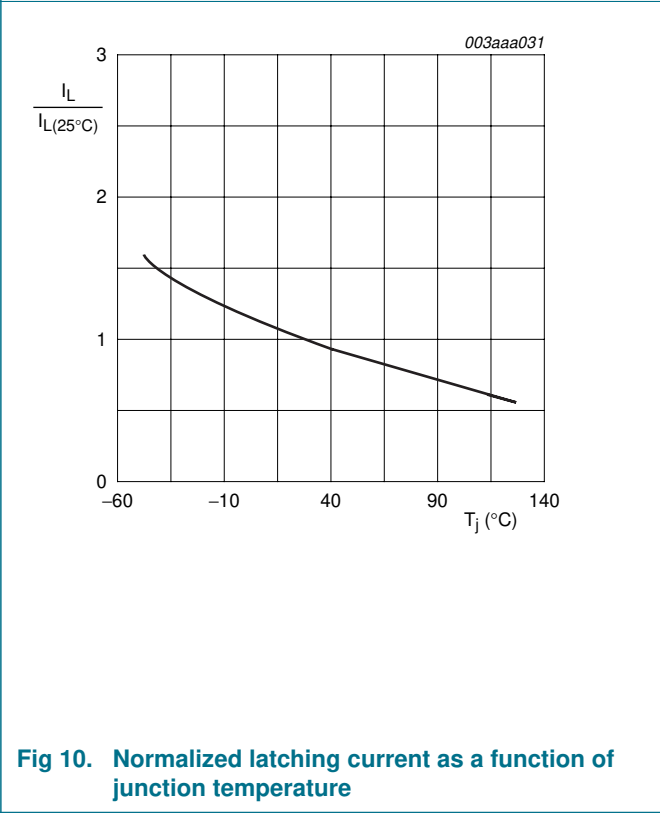
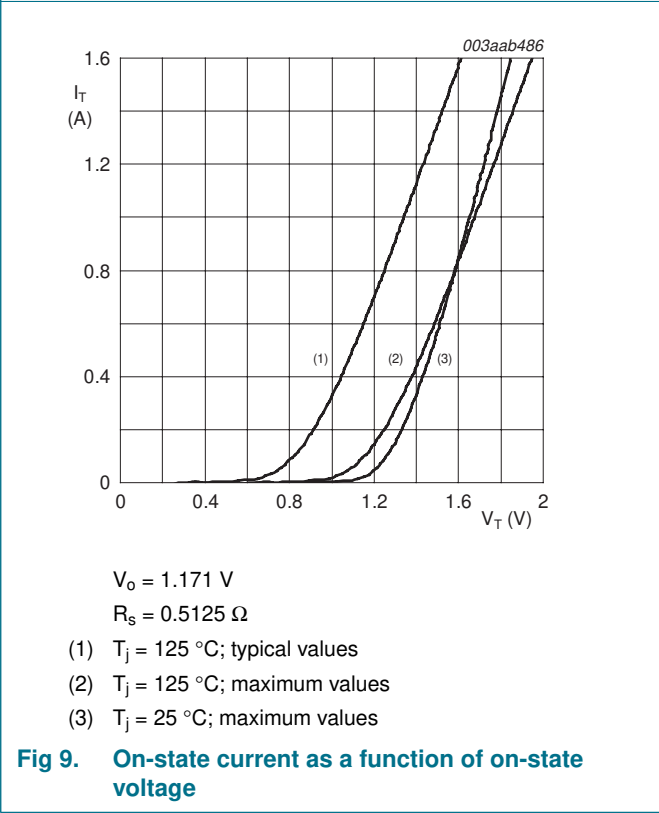
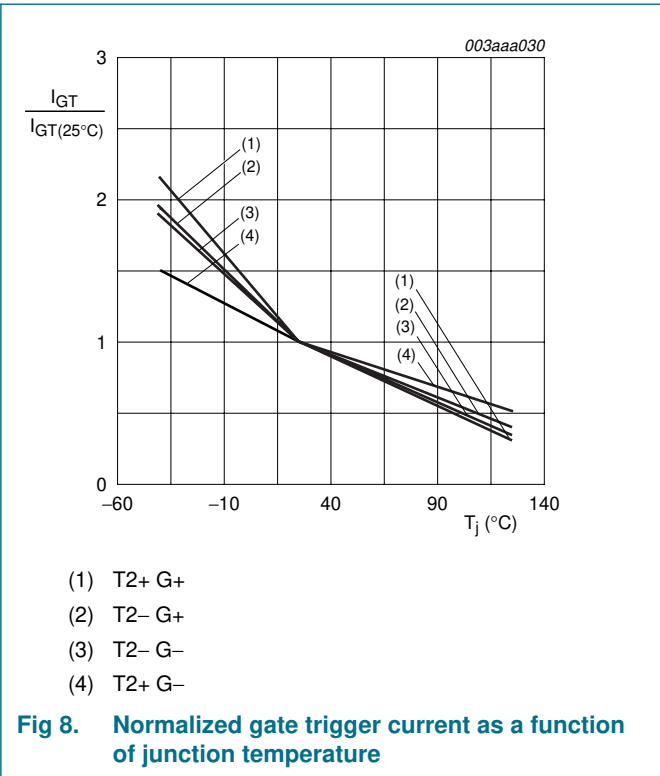
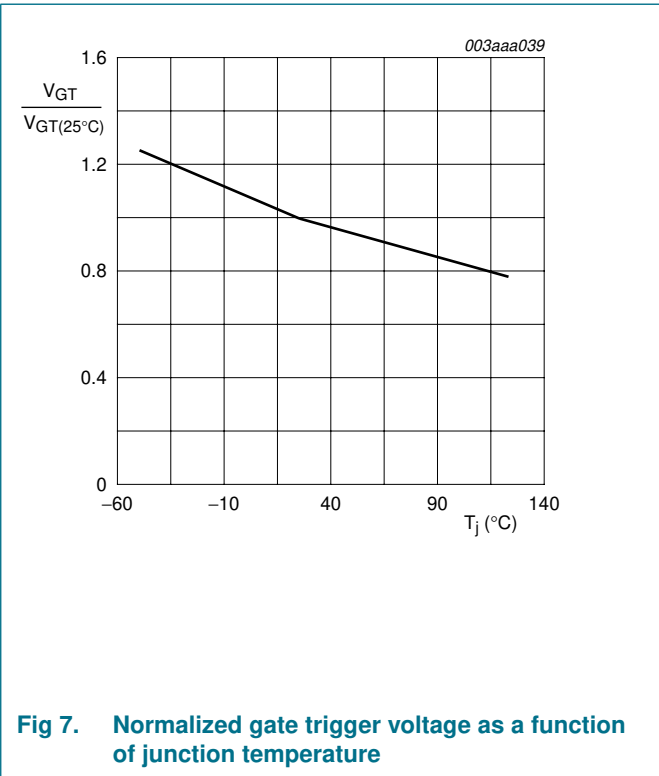


## 6. Characteristics

**Table 5. Characteristics**

$T_j = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

| Symbol                         | Parameter                             | Conditions                                                                                                                | Min | Typ  | Max | Unit             |
|--------------------------------|---------------------------------------|---------------------------------------------------------------------------------------------------------------------------|-----|------|-----|------------------|
| <b>Static characteristics</b>  |                                       |                                                                                                                           |     |      |     |                  |
| $I_{GT}$                       | gate trigger current                  | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; see <a href="#">Figure 8</a>                                                 |     |      |     |                  |
|                                |                                       | T2+ G+                                                                                                                    | -   | 1    | 5   | mA               |
|                                |                                       | T2+ G-                                                                                                                    | -   | 2    | 5   | mA               |
|                                |                                       | T2- G-                                                                                                                    | -   | 2    | 5   | mA               |
|                                |                                       | T2- G+                                                                                                                    | -   | 4    | 7   | mA               |
| $I_L$                          | latching current                      | $V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; see <a href="#">Figure 10</a>                                                |     |      |     |                  |
|                                |                                       | T2+ G+                                                                                                                    | -   | 1    | 10  | mA               |
|                                |                                       | T2+ G-                                                                                                                    | -   | 5    | 10  | mA               |
|                                |                                       | T2- G-                                                                                                                    | -   | 1    | 10  | mA               |
|                                |                                       | T2- G+                                                                                                                    | -   | 2    | 10  | mA               |
| $I_H$                          | holding current                       | $V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; see <a href="#">Figure 11</a>                                                | -   | 1    | 10  | mA               |
| $V_T$                          | on-state voltage                      | $I_T = 0.85\text{ A}$ ; see <a href="#">Figure 9</a>                                                                      | -   | 1.35 | 1.6 | V                |
| $V_{GT}$                       | gate trigger voltage                  | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; see <a href="#">Figure 7</a>                                                 | -   | 0.9  | 2   | V                |
|                                |                                       | $V_D = V_{DRM}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 110\text{ }^{\circ}\text{C}$                                              | 0.1 | 0.7  | -   | V                |
| $I_D$                          | off-state current                     | $V_D = V_{DRM(max)}$ ; $T_j = 125\text{ }^{\circ}\text{C}$                                                                | -   | 0.1  | 0.5 | mA               |
| <b>Dynamic characteristics</b> |                                       |                                                                                                                           |     |      |     |                  |
| $dV_D/dt$                      | rate of rise of off-state voltage     | $V_{DM} = 0.67 \times V_{DRM(max)}$ ; $T_j = 110\text{ }^{\circ}\text{C}$ ; exponential waveform; gate open circuit       | 30  | 45   | -   | V/ $\mu\text{s}$ |
| $dV_{com}/dt$                  | rate of change of commutating voltage | $V_{DM} = V_{DRM(max)}$ ; $T_j = 50\text{ }^{\circ}\text{C}$ ; $I_{TM} = 0.84\text{ A}$ ; $dI_{com}/dt = 0.3\text{ A/ms}$ | -   | 5    | -   | V/ $\mu\text{s}$ |
| $t_{gt}$                       | gate-controlled turn-on time          | $I_{TM} = 1\text{ A}$ ; $V_D = V_{DRM(max)}$ ; $I_G = 25\text{ mA}$ ; $dI_G/dt = 5\text{ A}/\mu\text{s}$                  | -   | 2    | -   | $\mu\text{s}$    |



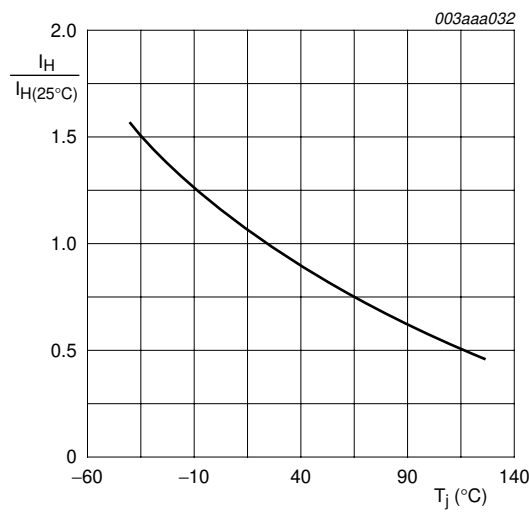


Fig 11. Normalized holding current as a function of junction temperature

7. Package outline

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

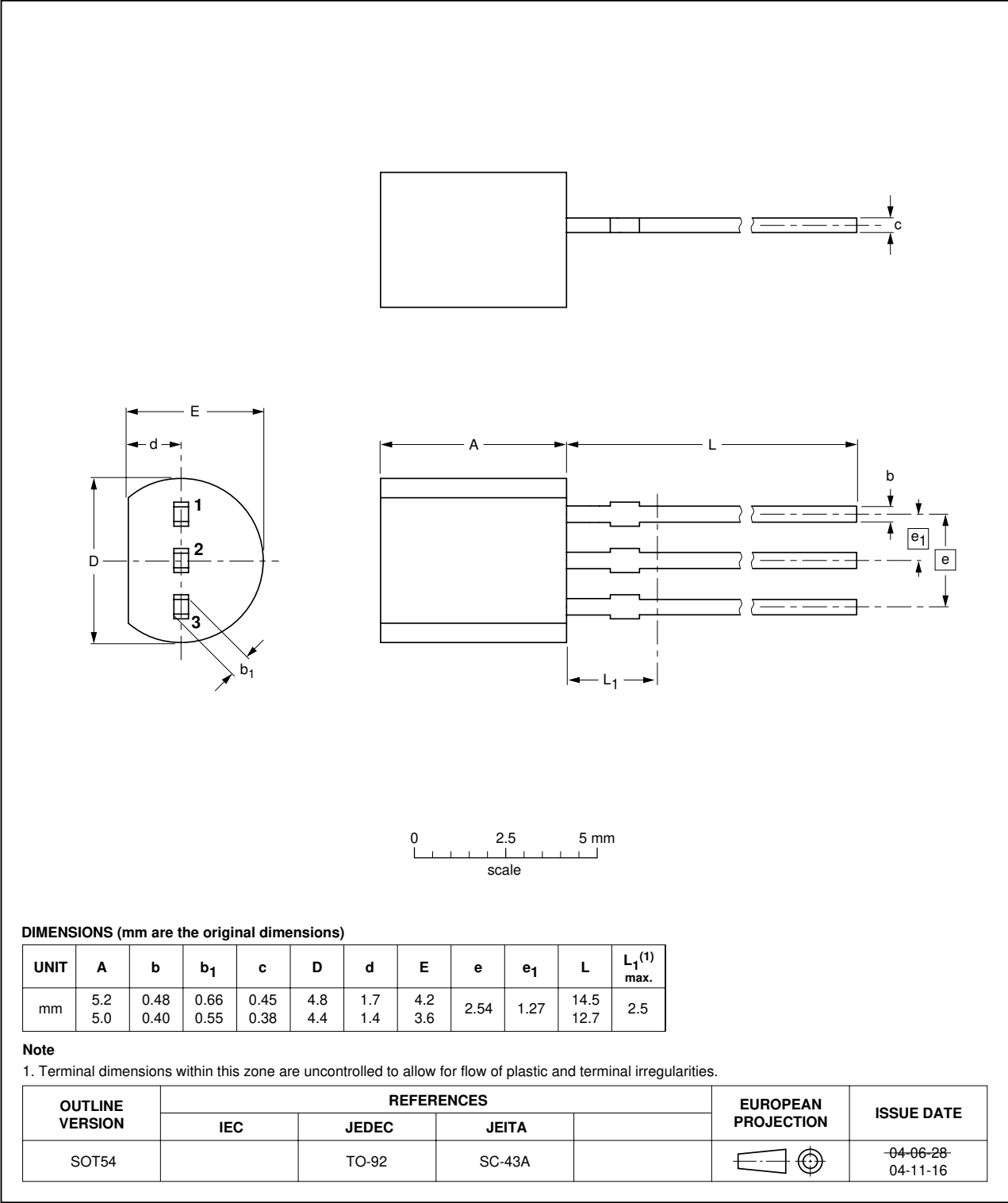


Fig 12. Package outline SOT54 (TO-92)

8. Revision history

Table 6. Revision history

| Document ID    | Release date | Data sheet status  | Change notice | Supersedes |
|----------------|--------------|--------------------|---------------|------------|
| BT1308_SER_D_1 | 20080226     | Product data sheet | -             | -          |

## 9. Legal information

### 9.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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11. Contents

1 Product profile ..... 1

1.1 General description..... 1

1.2 Features ..... 1

1.3 Applications ..... 1

1.4 Quick reference data..... 1

2 Pinning information..... 1

3 Ordering information..... 2

4 Limiting values..... 2

5 Thermal characteristics..... 5

6 Characteristics..... 6

7 Package outline ..... 9

8 Revision history..... 10

9 Legal information..... 11

9.1 Data sheet status ..... 11

9.2 Definitions..... 11

9.3 Disclaimers..... 11

9.4 Trademarks..... 11

10 Contact information..... 11

11 Contents ..... 12



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